							s	HEET 1 OF	
FOR	M PTO	-1449 U.S. DEPARTMEN PATENT AND TR	IT OF COMMERCE PADEMARK OFFICE	ATTY, DOCKET NO. MICRON.098CDV1	APPLICA 10/614	ATION NO. ,489		•	
OE JC	i3€∩pr	MATION DISCLOSURE STATI	MENT]				
1 70		BY APPLICANT		APPLICANT Basceri et al.					
(B)	(USE	EVERAL SHEETS IF NECES	SARY)	FILING DATE July 3, 2003	GROUP 2812				
ATENT & TR				July 3, 2003	2012			 -	
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D.V	1	6,339,527	01/2002	Farooq et al.					
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	3	5,822,175	10/1998	Azuma, Masamichi		,			
_	4	5,581,436	12/1996	Summerfelt et al.		777			
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EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS		LATION	
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EXAMINER INITIAL		0	THER DOCUMENTS	(INCLUDING AUTHOR, TITLE, DATE, PER	TINENT PAGES,	ETC.)			
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*EXAMINER: INITIAL IF CITATION CONSIDERED, WHETHER OR NOT CITATION IS IN CONFORMANCE WITH MPEP 609; DRAW LINE THROUGH CITATION IF NOT IN CONFORMANCE AND NOT CONSIDERED, INCLUDE COPY OF THIS FORM WITH NEXT COMMUNICATION TO APPLICANT.

SHEET 1 OF 1	

	FORM PTO-1449	U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE	ATTY. DOCKET NO. MICRON.098CDV1	APPLICATION NO. Unknown
		DISCLOSURE STATEMENT APPLICANT	APPLICANT Basceri et al.	
1	(USE SEVERAL	SHEETS IF NECESSARY)	FILING DATE Herewith	GROUP Unknown

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DV	C. Basceri, "An Important Failure Mechanism in MOCVD (Ba,Sr)TiO ₃ Thin Films: Resistance Degradation", Ferroelectric Thin Films IV, Materials Research Society, Symposium Proceedings Volume 493, 1998, pp. 9-14							
DY	Chung Ming Chu and Pang Lin, "Electric Properties and Crystal Structure of a (Ba,Sr)TiO ₃ Films Prepared at Low Temperatures on a LaNiO ₃ Electrode by Radio-Frequency Magnetron Sputtering", Appl. Phys. Lett., Vol. 70 (2), 13 January 1997, pp.249-51.							

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C	P FORM PTO-1449 U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE 2 0 7003 PROFINATION DISCLOSURE STATEMENT BY APPLICANT	ATTY: DOCKET NO. MICRON.098CDV1	APPLICATION NO. Unknown
١	8	APPLICANT Basceri et al.	
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DV	1.	6,238,966	05/29/01	Ueda et al.		Sales S			

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INITIAL							YES	NO			
PV	2.	0 617 439 A2	3/24/94	EPO							
DV	3.	JP 406333772A	12/2/94	Japan							
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